



Enhanced Fluoride over-coated Al Mirrors for FUV Astronomy

Manuel A. Quijada¹, Javier del Hoyo¹, Steve Rice¹, Felix Threat¹

¹ NASA-GSFC Code 551, Greenbelt, MD, United States.



ABSTRACT

Astronomical observations in the Far Ultraviolet (FUV) spectral region are some of the more challenging due to the very distant and faint objects that are typically searched for in cosmic origin studies such as origin of large scale structure, the formation, evolution, and age of galaxies and the origin of stellar and planetary systems. These challenges are driving the need to improve the performance of optical coatings over a wide spectral range that would increase reflectance in mirrors and reduced absorption in dielectric filters used in optical telescope for FUV observations. This paper will present recent advances in reflectance performance for Al+MgF₂ mirrors optimized for Lyman-alpha wavelength by performing the deposition of the MgF₂ overcoat at elevated substrate temperatures. We will also present optical characterization of little studied rare-earth fluorides such as GdF₃ and LuF₃ that exhibit low-absorption over a wide wavelength range and could therefore be used as high refractive index alternatives for dielectric coatings at FUV wavelengths.

Description and Objectives:

- To develop on a large scale (up to 1 meter diameter) coating of mirrors using a Al+MgF₂ coating process to enhance performance in the Far-Ultraviolet (FUV) spectral range
- Study other dielectric fluoride coatings and other deposition technologies such as Ion Beam Sputtering (IBS) that is known to produce the nearest to ideal morphology optical thin film coatings and thus low scatter
- Optimize deposition process of lanthanide trifluorides as high-index materials that when paired with either MgF₂ or LiF will enhance reflectance of Al mirrors at Lyman-alpha

Approach for Objective 1:

Retrofit a 2 meter coating chamber with heaters/thermal shroud to perform coating iterations at a high deposition temperatures (200-300°C) to further improve performance of protected Al mirrors with either MgF₂ or LiF overcoats

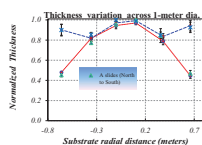
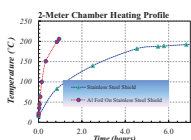
Tasks Description:

- Design and fabrication of internal heat shields for GSFC 2-meter Chamber.
- These wall panels were made out of stainless steel and were designed to easily interface with the existing internal configuration of the chamber.
- Optimized coating parameter for high FUV reflectance of a distribution of slides in center and out to a ~0.5 meter radius.

Physical Vapor Deposition (PVD):
Material is heated until it reaches vapor form. Material is deposited on the substrate where it condenses. Typical deposition rates are 10-100 Å/Sec.



- The images above show the fully assembled internal heat shields, power supply and quartz halogen lamps
- Heater was first tested on 08/13/13 and found maximum temperature reached was only 100 °C after 5 hours
- Doubled lamp power output from 500 W to 1000 W each (4000 W total)
- Additional testing yielded a maximum temperature of 130 °C
- Further testing done after wrapping heat shield panels with aluminum foil provide for a much quicker raise in temperature, reaching 220 °C in less than 1 hour (see graph below on the right)
- Performed a coating run with small 2x2in substrates located at various radius inside chamber (see graph below on the left)

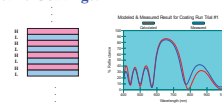


Approach for Objective 3:

Optimize deposition process of lanthanide trifluorides as high-index materials that when paired with either MgF₂ or LiF will enhance reflectance of Al mirrors at Lyman-alpha

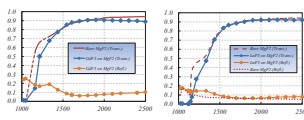
Tasks Description for FUV Dielectric Coatings:

- Choose a high-index (H) and low-index (L) pair combination
- Form a pair of (H,L) layers with thicknesses equal to a Quarter-Wave Optical thickness at the design wavelength.
- Repeat the stack above until desired reflectance is achieved.

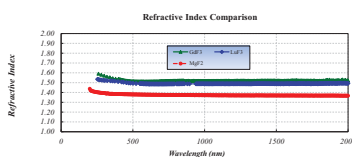


Options for FUV coating candidates: Low Index: MgF₂ (n=1.38)
High Index: LuF₃, GdF₃

The two graphs below show transmission and reflectance of GdF₃ (right) and LuF₃ (left) films grown on MgF₂ substrates. These data are used to extract refractive index for both of these materials.

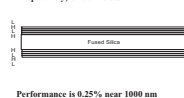


The data on the graphs shown above were used to obtain refractive index (n and k) for MgF₂, GdF₃, and LuF₃ films. The results are shown in graph



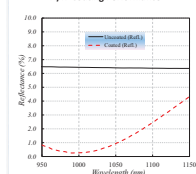
Example of A/R coating design and fabrication:

- A/R to suppress FS reflection losses near 1000 nm
- Design includes 2 layer pairs of GdF₃(H)/MgF₂(L) (181 and 200 nm respectively) on both sides



Performance is 0.25% near 1000 nm

A/R Coating Performance



Spectral Characterization:

Spectrometer used to collect spectral scan of transmission and/or reflectance from 90 nm to 2500 nm are two gratings instrument shown below



PE Specifications

- Double-beam ratio recording grating monochromator
- Wavelength range: 180-3300 nm; Resolution: .05-5 nm
- Quartz Tungsten Halogen and D2 lamps
- Lead-sulfide and PMT detectors
- Photometric Range: Up to 38 Absorbance units (with attenuation)
- Universal Reflectance Accessory for normalized reflectance between 8° and 68° angle of incidence.

•ACTON Specifications

- One-meter high-vacuum monochromator (1200 grooves/mm)
- Wavelength range from 30 nm to 325 nm.
- Windowless hydrogen-purged light source (discrete H2 emission lines between 90 nm and 160 nm and a continuum at higher λ)
- Photomultiplier Cathode Tube with light-pipe equipped with a fluorescence coating (sodium salicylate) for converting FUV to visible light
- Sample compartment allows absolute transmission and reflectance measurements at varying angles of incidence (12-68°) without the need of a reference

Al+MgF₂ Coating Performance:

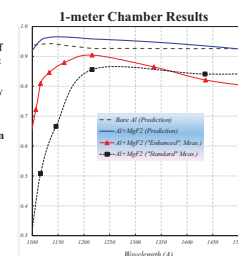
3-step coating process:

- Al is coated on the substrate at room temperature to the planned layer thickness
- As soon as possible after the Al deposition, overcoat the Al layer and substrate at room temperature with a thin 4-5 nm layer of MgF₂ in order to protect the Al from oxidation and contamination.
- Heat the substrate to 200-300 °C and finish the planned final MgF₂ thickness MgF₂.

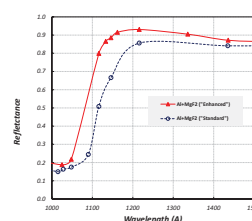
Results:

1-meter Chamber Results

- Predicted vs. measured reflectance of bare Al and Al+MgF₂ reflectance (Al: 50.0 nm; MgF₂: 25.0nm)
- Enhanced performance is obtained by heating (~220 °C) substrate during MgF₂ deposition
- Reflectance is > 80% even at 115.0 nm



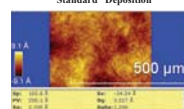
2-meter Chamber Results



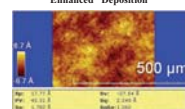
- Recently started test run in center of 2-meter chambers to optimize the 3-step process for depositing Al+MgF₂ coatings
- Graph on left display reflectance data taken of test coupons done in this chamber.
- "Standard" test sample was prepared under normal conditions on 08/22/2013
- "Enhanced" was produced with a "hot" (220°C MgF₂ deposition done on 11/27/2103.
- These data represent an important milestone

Micro-roughness Al+MgF₂ Films

"Standard" Deposition



"Enhanced" Deposition



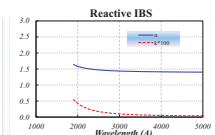
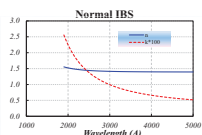
AMC1301C <20 mag/μm² average			
	PV (Å)	Sq (Å)	
top left	75.38	6.146	
top right	101.2	5.196	
center	124	4.651	
bottom left	206.1	3.607	
bottom right	100	3.262	
average	120.97	4.3364	

AMC1315A <20 mag/μm² average			
	PV (Å)	Sq (Å)	
top left	43.15	2.249	
top right	40.19	2.331	
center	50.86	3.364	
bottom left	44.39	2.923	
bottom right	39.83	3.454	
average	46.34	2.9922	

The tables above show micro-roughness results on two classes of Al+MgF₂ coatings done with the MgF₂ layer deposited at ambient (left) and at elevated (right) temperatures. The table on the right shows the average roughness for the elevated MgF₂ depositions is 30% smaller.

Conclusions

- Reported gains in FUV reflectivity of Al+MgF₂ and Al+LiF mirrors by employing a 3-step process during PVD coating deposition of these materials.
- Successfully demonstrated gains in FUV reflectance using a large 2-meter chamber that will allow coating up to 1 meter diameter optics.
- Characterization of lanthanide tri-fluoride material candidates to determine their FUV transparency for development of dielectric coatings.
- Will plan to refurbish a second 1-meter chamber to perform IBS film deposition of MgF₂/LiF materials.



- Optimization and characterization of MgF₂ films using the IBS process did not give satisfactory results (see graphs below)
- Problem is thought to be traced at degradation of cathode filament due to reactive fluoride containing gas (Freon) in chamber